

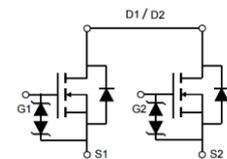
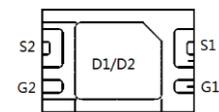
Features

- N-Channel, 3.3V Logic Level Control
- Enhancement mode
- Very low on-resistance $R_{DS(on)}$ @ $V_{GS}=3.3V$
- ESD Protection
- 100% Avalanche Tested
- Pb-free lead plating; RoHS compliant



Part ID	Package Type	Marking	Tape and reel information
VSA007N02ED	TDFN2x3-6L	007N02ED	3000pcs/Reel

V_{DS}	20	V
$R_{DS(on),TYP} @ V_{GS}=5.0V$	6.5	m Ω
$R_{DS(on),TYP} @ V_{GS}=3.3V$	7.0	m Ω
I_D	12	A

TDFN2x3-6L


Maximum ratings, at $T_j=25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter	Rating	Unit	
$V_{(BR)DSS}$	Drain-Source breakdown voltage	20	V	
I_S	Diode continuous forward current	$T_C=25^\circ\text{C}$	12	A
I_D	Continuous drain current	$T_C=25^\circ\text{C}$	12	A
		$T_A=100^\circ\text{C}$	7.6	A
I_{DM}	Pulse drain current tested ①	$T_C=25^\circ\text{C}$	48	A
EAS	Avalanche energy, single pulsed ②	$L=0.5\text{mH}$	16	mJ
P_D	Maximum power dissipation	$T_A=25^\circ\text{C}$	2	W
V_{GS}	Gate-Source voltage	± 12	V	
$T_{STG} T_J$	Storage and operating temperature range	-55 to 175	$^\circ\text{C}$	

Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta JC}$	Thermal Resistance-Junction to Case	45	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	62.5	$^\circ\text{C/W}$

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
Static Electrical Characteristics @ T_c = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =250μA	20	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current(T _c =25°C)	V _{DS} =16V, V _{GS} =0V	--	--	1	μA
	Zero Gate Voltage Drain Current(T _c =125°C)	V _{DS} =16V, V _{GS} =0V	--	--	100	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±12V, V _{DS} =0V	--	--	±10	uA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	0.5	0.8	1.2	V
R _{DS(ON)}	Drain-Source On-State Resistance ^③	V _{GS} =5.0V, I _D =5A	--	6.5	9.0	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ^③	V _{GS} =3.3V, I _D =5A	--	7.0	9.5	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ^③	V _{GS} =2.5V, I _D =2A	--	9.0	11.0	mΩ
Dynamic Electrical Characteristics @ T_c = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =10V, V _{GS} =0V, f=1MHz	--	1310	--	pF
C _{oss}	Output Capacitance		--	260	--	pF
C _{rss}	Reverse Transfer Capacitance		--	235	--	pF
Q _g	Total Gate Charge	V _{DS} =16V, I _D =11A, V _{GS} =4.5V	--	15	--	nC
Q _{gs}	Gate-Source Charge		--	3	--	nC
Q _{gd}	Gate-Drain Charge		--	7	--	nC
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DD} =16V, I _D =5.5A, R _G =3Ω, V _{GS} =4.5V	--	31	--	nS
t _r	Turn-on Rise Time		--	87	--	nS
t _{d(off)}	Turn-Off Delay Time		--	69	--	nS
t _f	Turn-Off Fall Time		--	37	--	nS
Source- Drain Diode Characteristics @ T_c = 25°C (unless otherwise stated)						
V _{SD}	Forward on voltage	I _{SD} =5A, V _{GS} =0V	--	0.70	1.2	V
t _{rr}	Reverse Recovery Time	T _j =25°C, I _{sd} =10A, V _{GS} =0V di/dt=100A/μs	--	47	--	nS
Q _{rr}	Reverse Recovery Charge		--	62	--	nC

NOTE:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Limited by T_{Jmax}, starting T_J = 25°C, L = 0.5mH, R_G = 25Ω, I_{AS} = 8A, V_{GS} = 10V. Part not recommended for use above this value
- ③ Pulse width ≤ 300μs; duty cycle ≤ 2%.

Typical Characteristics

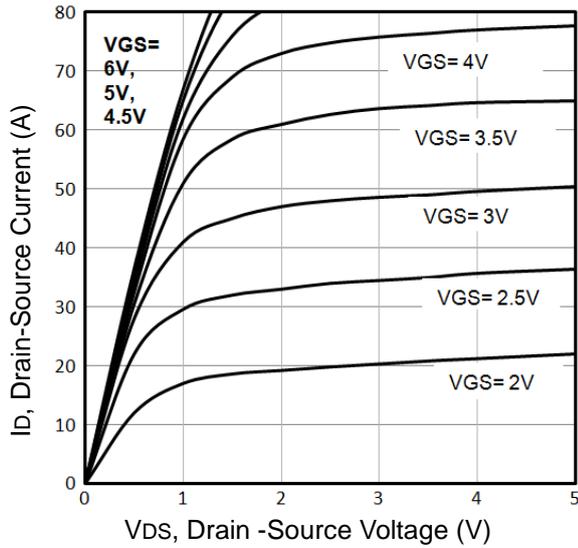


Fig1. Typical Output Characteristics

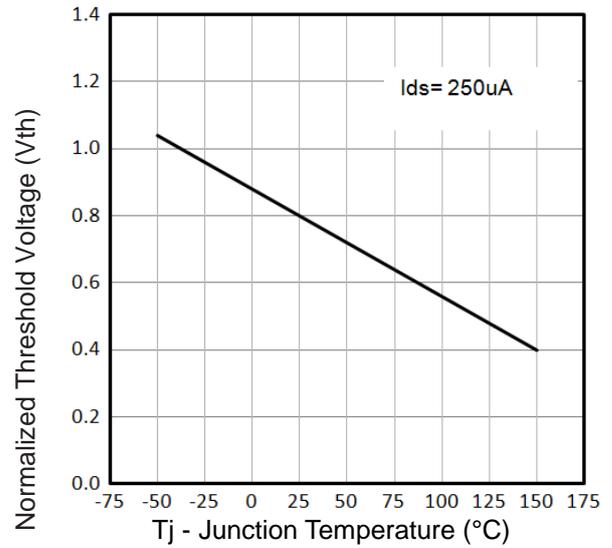


Fig2. Normalized Threshold Voltage Vs. Temperature

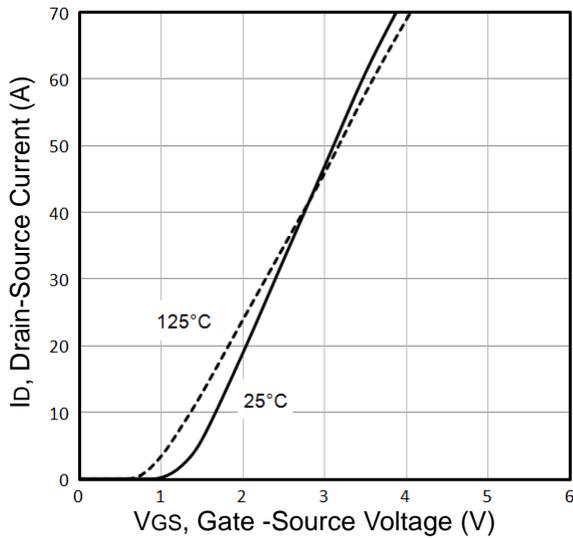


Fig3. Typical Transfer Characteristics

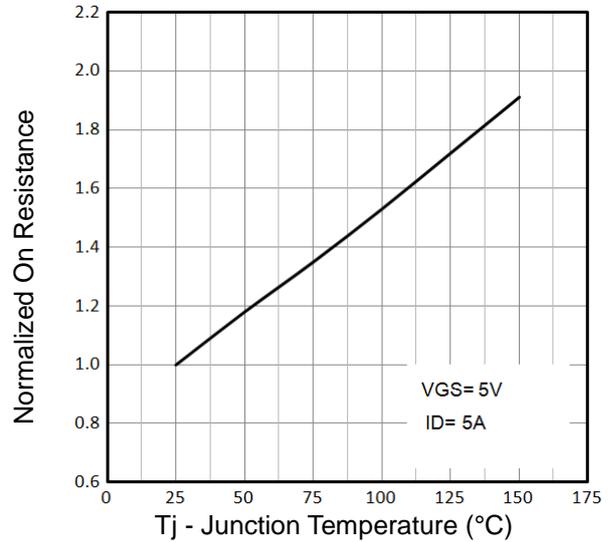


Fig4. Normalized On-Resistance Vs. Temperature

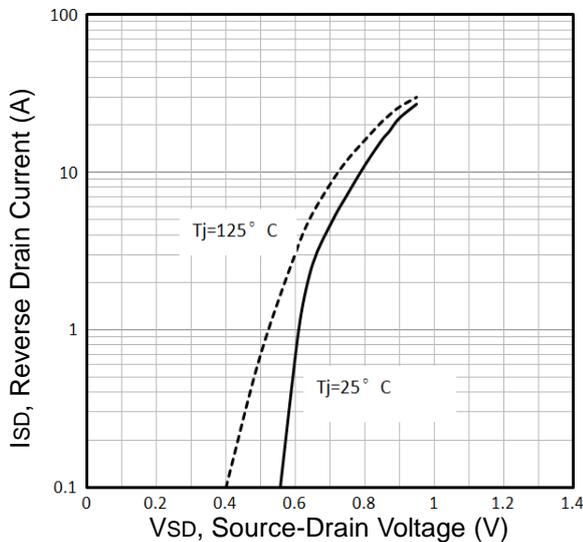


Fig5. Typical Source-Drain Diode Forward Voltage

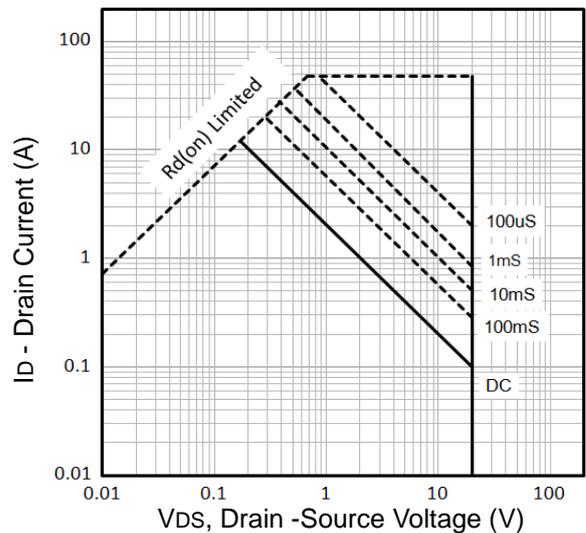


Fig6. Maximum Safe Operating Area

Typical Characteristics

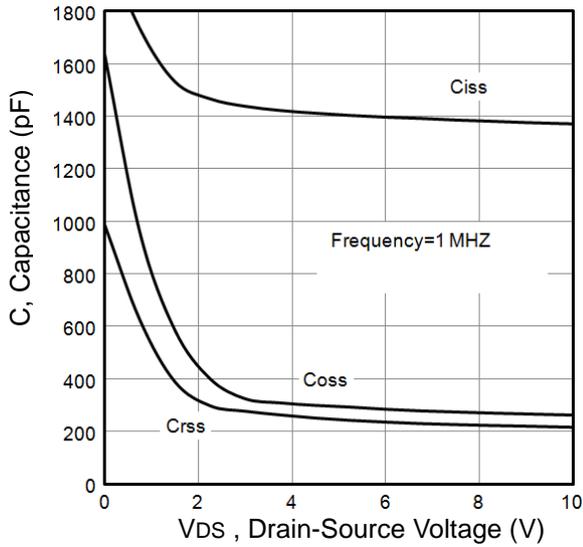


Fig7. Typical Capacitance Vs. Drain-Source Voltage

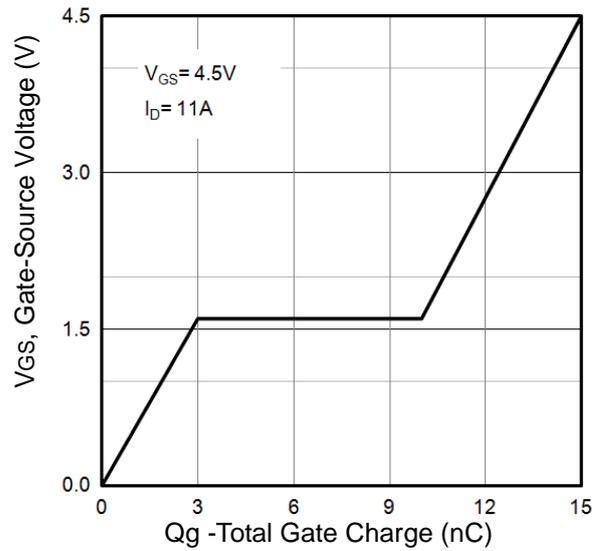


Fig8. Typical Gate Charge Vs. Gate-Source

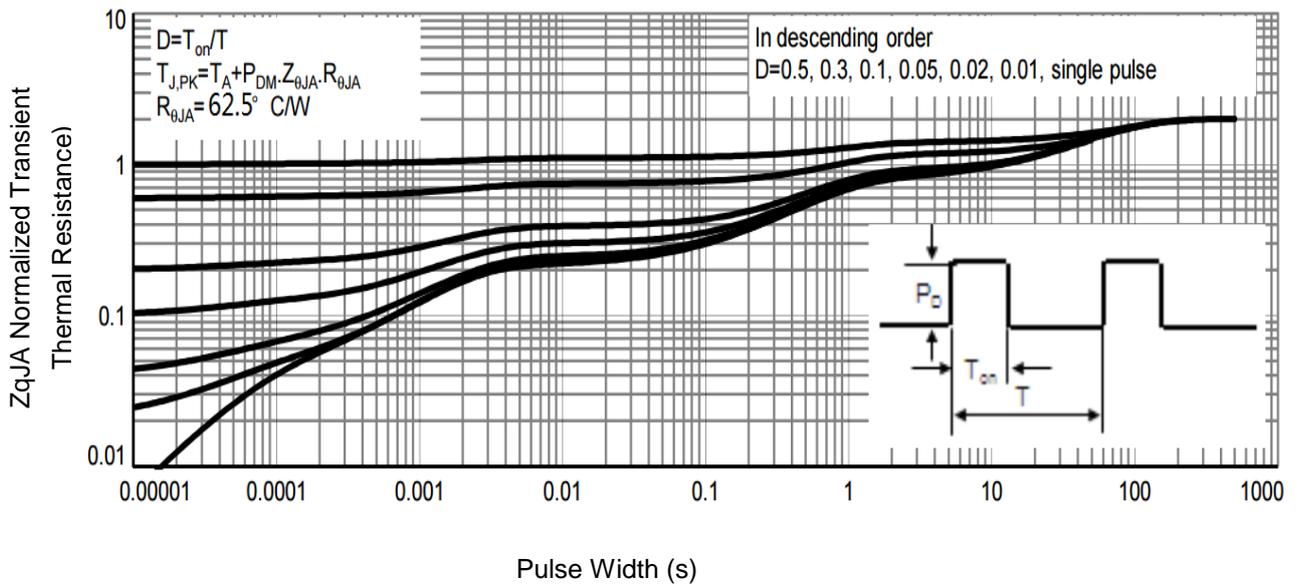


Fig9. Normalized Maximum Transient Thermal Impedance

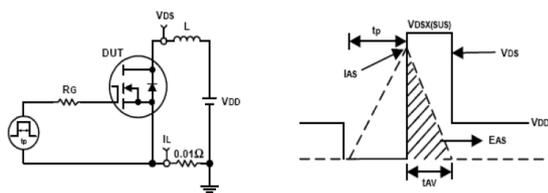


Fig10. Unclamped Inductive Test Circuit and waveforms

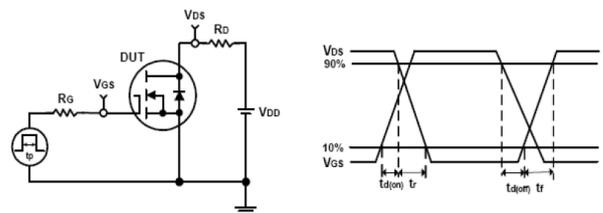
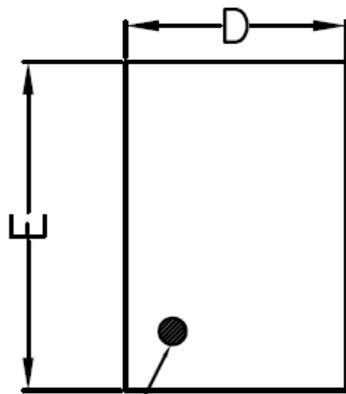


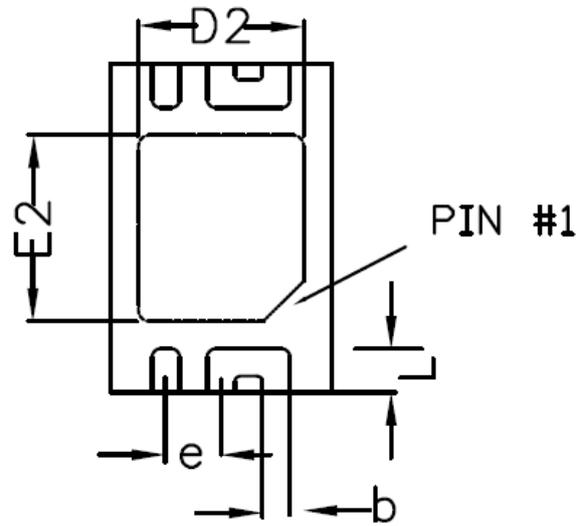
Fig11. Switching Time Test Circuit and waveforms

TDFN2x3-6L Package Outline Data

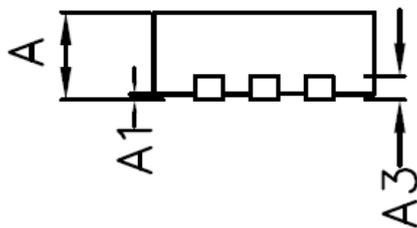


PIN 1 DOT
BY MARKING

TOP VIEW



BOTTOM VIEW



SIDE VIEW

DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	0.70	0.80	0.85	A ₁	0.00	--	0.05
A ₃	0.195	0.200	0.211	D	1.95	2.00	2.05
D ₂	1.45	1.50	1.55	E	2.95	3.00	3.05
E ₂	1.65	1.70	1.75	b	0.20	0.25	0.30
L	0.35	0.40	0.45	e	0.50BSC		